



NV4V31MF

Blue-Violet Laser Diode 405 nm Blue-Violet Laser Light Source

Data Sheet

R08DS0045EJ0200 Rev.2.00 Jun 20, 2013

DESCRIPTION

The NV4V31MF is a blue-violet laser diode with a wavelength of 405 nm. A newly developed LD chip structure achieves a high optical power output of 175 mW (CW) at up to 85°C. The NV4V31MF can provide excellent linearity from low to high output at high temperatures, and reduces the unevenness of beam divergence.

FEATURES

<R>

High optical output power
 Peak emission wavelength
 Peak emission wavelength
 λ = 405 nm TVP

Peak emission wavelength λ_p = 405 nm TYP.
 Single transverse mode (lateral)

• Wide operating temperature range $T_C = -5$ to +85°C

• ϕ 3.8 mm small CAN package

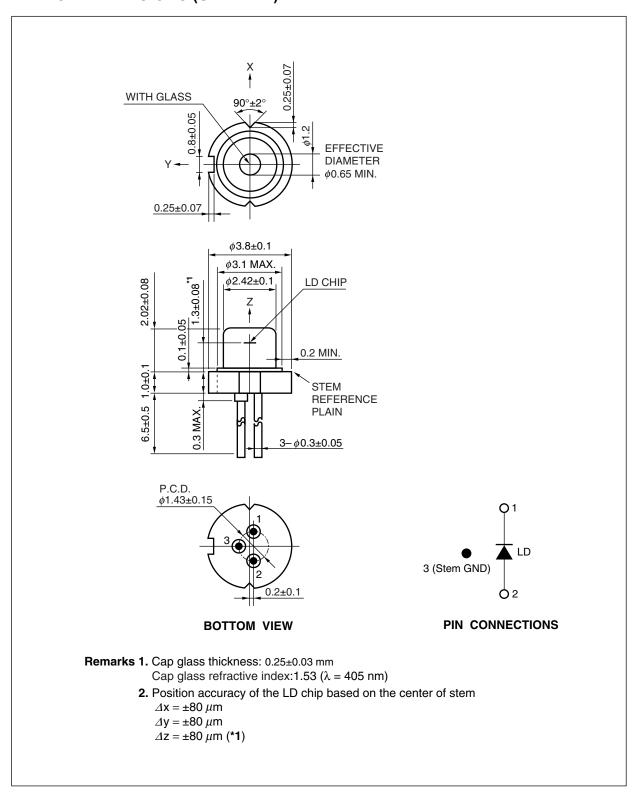
APPLICATIONS

• Blue-violet laser light source



The mark <R> shows major revised points.

<R> PACKAGE DIMENSIONS (UNIT: mm)





<R> ORDERING INFORMATION

Part Number	Order Number	Rank	Packing Style
NV4V31MF	NV4V31MF-A	GV	Tray Packing (250 p/Tray), Without data
		KV	Individual Packing (for samples), Without data

<R> ABSOLUTE MAXIMUM RATINGS (T_C = 25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Optical Output Power (CW)	Po	180	mW
Reverse Voltage of LD	V _R	2	V
Operating Case Temperature	T _C	−5 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C

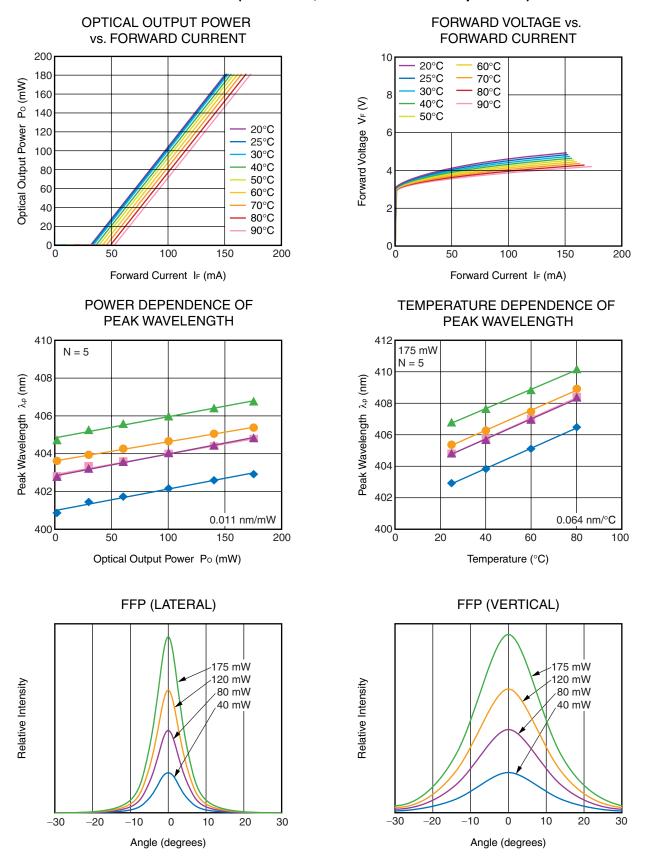
RECOMMENDED OPERATING CONDITIONS $(T_c = 25^{\circ}C, unless otherwise specified)$

Parameter	Symbol	MAX.	Unit
Optical Output Power (CW)	Po	175	mW

ELECTRO-OPTICAL CHARACTERISTICS (T_C = 25°C, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Threshold Current	I _{th}	CW		35	55	mA
Operating Current	I _{op}	CW, P _o = 175 mW		150	200	mA
Optical Voltage	V_{op}	CW, P _o = 175 mW		5.0	6.5	V
Slope Efficiency	η_{d}	CW, P _o = 20 mW, 175 mW	1.1	1.55		W/A
Peak Wavelength	λ_{p}	CW, P _o = 175 mW	400	405	415	nm
Beam Divergence (lateral)	θ_{ll}	CW, P _o = 175 mW	6	9	12	deg.
Beam Divergence (vertical)	$ heta_{\!\perp}$		15	20	25	
Position Accuracy Angle (lateral)	$\Delta heta_{ll}$	CW, P _o = 175 mW	-3	0	3	deg.
Position Accuracy Angle (vertical)	$arDelta heta_{\!\perp}$		-3	0	3	

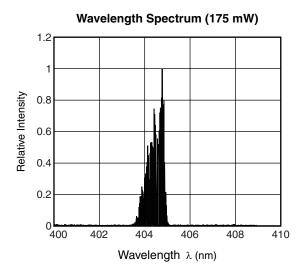
<R> TYPICAL CHARACTERISTICS (T_c = 25°C, unless otherwise specified)



Remark The graphs indicate nominal characteristics.

Wavelength Spectrum (100 mW) 1.2 1.2 1 0.8 0.6 0.4 0.2 400 400 402 404 406 408 410 Wavelength λ (nm)

Remark The graphs indicate nominal characteristics.



R> NOTES ON HANDLING

- 1. Recommended soldering conditions
 - Peak Temperature ≤ 350°C
 Time ≤ 3 seconds
 - Soldering of leads should be made at the point 2.0 mm from the root of the lead
 - This device cannot be mounted using reflow soldering.
- 2. Usage cautions
 - (1) Take the following steps to ensure that the device is not damaged by static electricity.
 - Wear an antistatic wrist strap when soldering the device.
 - We recommend a strap with a 1 M Ω resistor.
 - Make sure that the work table and soldering iron are grounded.
 - Make sure that the soldering iron does not leak.
 - (2) Do not subject the package to undue stress.

The package has a tensile strength of 1N or less.

Do not exceed this rating. Also, avoid bending the leads as much as possible.

If the leads must be bent, bend them only once, making sure to anchor the stem base of the lead.

- (3) Do not allow the cap glass of the package to become scratched or dirty. Also, do not subject the cap glass to external force.
- (4) Be sure to attach a heat sink to sufficiently dissipate heat.
- (5) Use the device as soon as possible after opening the bag.

SAFETY INFORMATION ON THIS PRODUCT





VISIBLE LASER RADIATION
AVOID EVE OR SKIN EXPOSURE TO
DIRECT OR SCATTERED RADIATION
OUTPUT POWER 3W MAX
WAVELENGTH 400 to 680nm
CLASS IV LASER PRODUCT

SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

Warning

Laser Beam

A laser beam is emitted from this diode during operation.

If the laser beam or its reflection enters your eye, it may cause injury to the eye or loss of eyesight. (Note that, depending on the wavelength of the beam, the laser beam might not be visible.)

- Do not look directly into the laser beam.
- Avoid exposure to the laser beam, any reflected or collimated beam.



Revision History

NV4V31MF Data Sheet

		Description		
Rev.	Date	Page	Summary	
0.01	Sep 08, 2011	-	First edition issued	
1.00	Mar 05, 2012	Throughout	Preliminary Data Sheet -> Data Sheet	
		p.3	Modification of ORDERING INFORMATION	
		p.4, 5	Addition of TYPICAL CHARACTERISTICS	
2.00	Jun 20, 2013	p.1	Modification of FEATURES	
		p.2	Modification of PACKAGE DIMENSIONS	
		p.3	Modification of ORDERING INFORMATION	
			Modification of ABSOLUTE MAXIMUM RATINGS	
		p.4	Modification of TYPICAL CHARACTERISTICS	
		p.6	Modification of NOTES ON HANDLING	
		p.7	Modification of SAFETY INFORMATION ON THIS PRODUCT	

NOTICE

- 1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. California Eastern Laboratories and Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 2. California Eastern Laboratories has used reasonable care in preparing the information included in this document, but California Eastern Laboratories does not warrant that such information is error free. California Eastern Laboratories and Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 3. California Eastern Laboratories and Renesas Electronics do not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of California Eastern Laboratories or Renesas Electronics or others.
- 4. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part. California Eastern Laboratories and Renesas Electronics assume no responsibility for any losses incurred by you or third parties arising from such alteration, modification, copy or otherwise misappropriation of Renesas Electronics product.
- 5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots etc. "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; and safety equipment etc. Renesas Electronics products are neither intended nor authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems, surgical implantations etc.), or may cause serious property damages (nuclear reactor control systems, military equipment etc.). You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application for which it is not intended. California Eastern Laboratories and Renesas Electronics product for which the product is not intended by California Eastern Laboratories or Renesas Electronics.
- 6. You should use the Renesas Electronics products described in this document within the range specified by California Eastern Laboratories, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. California Eastern Laboratories shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 7. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or systems manufactured by you.
- 8. Please contact a California Eastern Laboratories sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. California Eastern Laboratories and Renesas Electronics assume no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 9. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You should not use Renesas Electronics products or technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. When exporting the Renesas Electronics products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations.
- 10. It is the responsibility of the buyer or distributor of California Eastern Laboratories, who distributes, disposes of, or otherwise places the Renesas Electronics product with a third party, to notify such third party in advance of the contents and conditions set forth in this document, California Eastern Laboratories and Renesas Electronics assume no responsibility for any losses incurred by you or third parties as a result of unauthorized use of Renesas Electronics products.
- 11. This document may not be reproduced or duplicated in any form, in whole or in part, without prior written consent of California Eastern Laboratories.
- 12. Please contact a California Eastern Laboratories sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- NOTE 1: "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- NOTE 2: "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.
- NOTE 3: Products and product information are subject to change without notice.

CEL Headquarters • 4590 Patrick Henry Drive, Santa Clara, CA 95054 • Phone (408) 919-2500 • www.cel.com

For a complete list of sales offices, representatives and distributors,
Please visit our website: www.cel.com/contactus